GBP



GBP2005 THRU GBP210

VOLTAGE RANGE CURRENT 50 to 1000 Volts 2.0 Ampere

RoHS

CURRENT

Features

Glass passivated chip junction

· Ideal for surface mounted applications

Low leakage

· High forward surge current capability

High temperature soldering guaranteed:
260 ℃/10 seconds at terminals

Mechanical Data

· Case: Molded plastic body

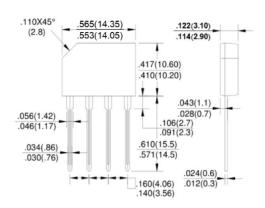
Epoxy: UL94V-0 rate flame retardant

· Polarity: Molded on body

• LeadP: Plated terminals solderable per MIL-STD-202E

method 208C

Weight: 0.039 ounce, 1.1gram



Dimensions in milimeters

Package: GBP

Maximum Ratings and Electrical Characteristics

Ratings at 25[™] ambient temperature unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load

For capacitive load derate current by 20%

TYPE NUMBER		SYMBOL S	GBP 2005	GBP 201	GBP 202	GBP 204	GBP 206	GBP 208	GBP 210	UNIT
Maximum Reverse Peak Repetitive Voltage		V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage		V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Output Current, 0.06"(1.5mm) lead length at T _c =100 ℃		I _(AV)	2.0					Amps		
Peak Forward Surge Current 8.3ms single half sine wave superimposed on rated load (JEDEC Method)		I _{FSM}	50					Amps		
Rating for Fusing (t<8.3ms)		l²t	18				A ² s			
Maximum Instantaneous Forward Voltage drop Per Bridge element 2.0A		V _F	1.1					Volts		
Maximum Reverse Current at rated DC blocking voltage per element	TA=25℃		5						μAmps	
	TA=125℃	l _R	50							
Typical Thermal Resistance (NOTE 2)		Rөлс	6					°C/W		
		R _{⊝JL}	5					°C/W		
		R⊚JA	42					°C/W		
Operating and Storage Temperature Range		T _J ,T _{ST}	-55 to +150					$^{\circ}$ C		

Notes:

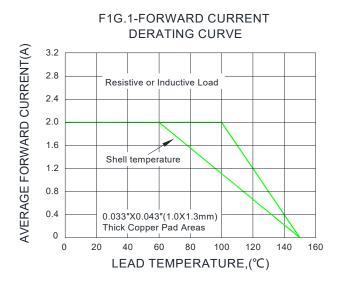
- 1. Measured at 1.0MHz and applied reverse voltage of 4.0 Volts.
- 2. Unit mounted on P.C.B. with 0.033"×0.043"(1.00mm×1.30mm) copper pads.

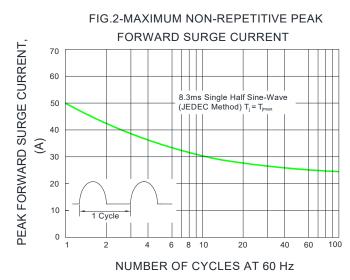


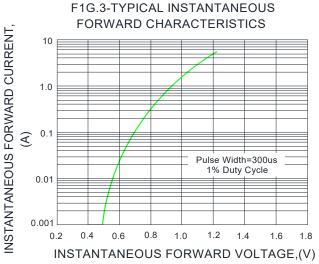
GBP2005 THRU GBP210

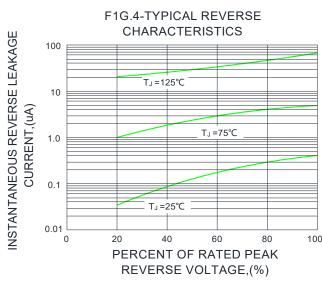
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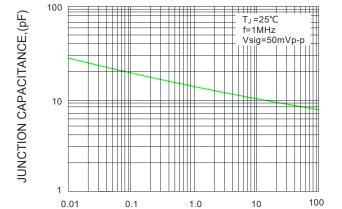
Ratings and Characteristic Curves (TA=25°C unless otherwise noted)











REVRESE VOLTAGE,(V)

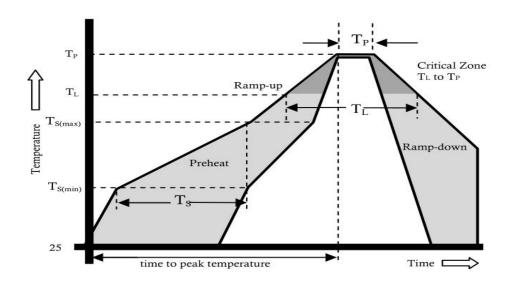
F1G.5-TYPICAL JUNCTION CAPACITANCE



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Reflow Profile



Reflow Condition		Pb-Free Assembly				
	Temperature Min.	+150°C				
Pre Heat	Temperature Max.	+200°C				
	Time(Min to Max)	60-180 secs.				
Average ramp up rate(Liquidus $Temp(T_L)$ to peak)		3°C/sec. Max.				
$T_{\text{S}}(\text{max})$ to T_{L} - Ramp-up Rate		3°C/sec. Max.				
Reflow	Temperature (T∟)(Liquidus)	+217°C				
	Temperature (T _L)	60-150 secs.				
Peak Temp (T _P)		+(260+0/-5)°C				
Time within 5°C of actual Peak Temp (T _P)		25 secs.				
Ramp-down Rate		6°C/sec. Max.				
Time 25°C to peak Temp (T _P)		8 min. Max.				
Do not exceed		+260°C				



SINGLE-PHASE SILICON BRIDGE RECTIFIER

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Disclaimer

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